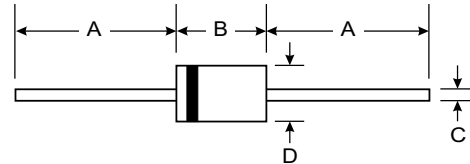


### Features

- Glass Passivated Die Construction
- Super-Fast Recovery Time For High Efficiency
- Low Forward Voltage Drop and High Current Capability
- Surge Overload Rating to 35A Peak
- Ideally Suited for Automated Assembly
- Plastic Material: UL Flammability Classification Rating 94V-0



### Mechanical Data

- Case: Molded Plastic
- Terminals: Solder Plated Terminal - Solderable per MIL-STD-202, Method 208
- Marking: MUR140: R140  
MUR160: R160
- Polarity: Cathode Band
- Weight: 0.35 grams (approx.)
- Mounting Position: Any

DO-41 Plastic		
Dim	Min	Max
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics

@ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	MUR140	MUR160	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	400	600	V
Working Peak Reverse Voltage	V <sub>RWM</sub>			
DC Blocking Voltage	V <sub>R</sub>			
RMS Reverse Voltage	V <sub>R(RMS)</sub>	283	424	V
Average Rectified Output Current @ T <sub>T</sub> = 120°C	I <sub>O</sub>	1.0		A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	35		A
Forward Voltage @ I <sub>F</sub> = 1.0A, T <sub>J</sub> = 25°C @ I <sub>F</sub> = 1.0A, T <sub>J</sub> = 150°C	V <sub>FM</sub>	1.25 1.05		V
Peak Reverse Current at Rated DC Blocking Voltage @ T <sub>A</sub> = 25°C @ T <sub>A</sub> = 150°C	I <sub>RM</sub>	5.0 150		μA
Reverse Recovery Time (Note 2)	t <sub>rr</sub>	50		ns
Reverse Recovery Time (Note 3)	t <sub>rr</sub>	75		ns
Forward Recovery Time (Note 4)	t <sub>fr</sub>	50		ns
Typical Junction Capacitance (Note 1)	C <sub>j</sub>	45		pF
Typical Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	72		K/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +175		°C

- Notes:
1. Measured at 1.0MHz and applied reverse voltage of 0V DC.
  2. Measured with I<sub>F</sub> = 0.5A, I<sub>R</sub> = 1.0A, I<sub>rr</sub> = 0.25A. See Figure 5.
  3. Measured with I<sub>F</sub> = 1A, di/dt = 50A/us.
  4. Measured with I<sub>F</sub> = 1.0A, di/dt = 100A/μs, Duty Cycle ≤ 2.0%.

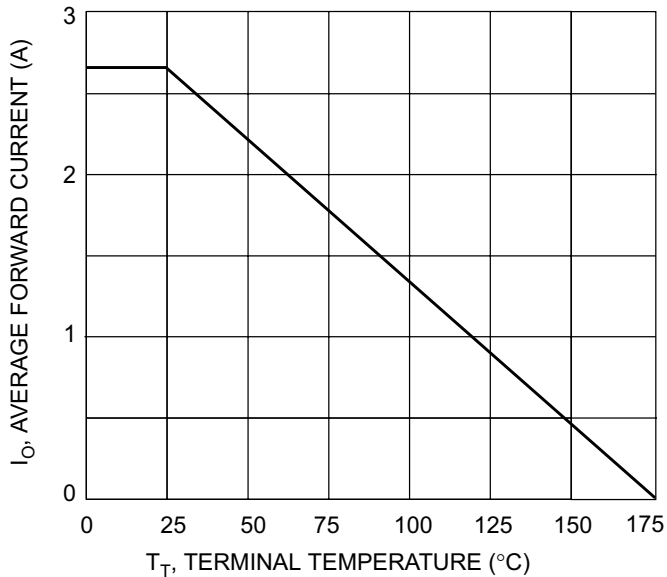


Fig. 1 Forward Current Derating Curve

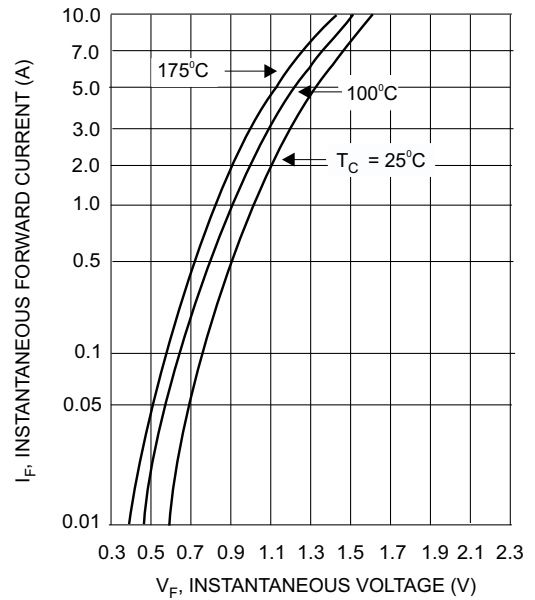


Fig. 2 Typical Forward Current

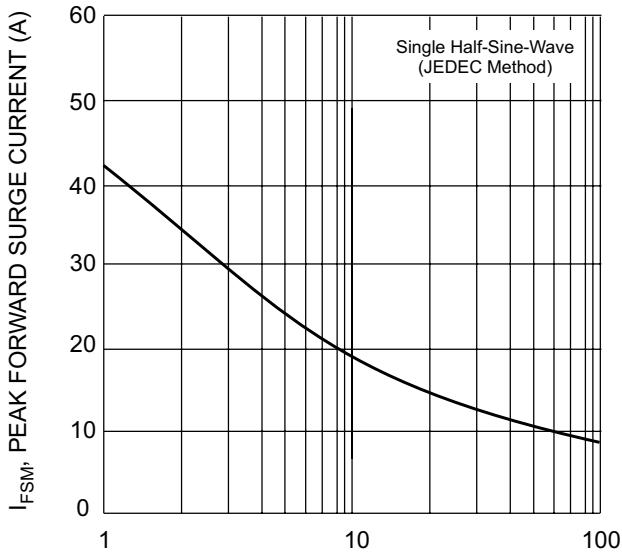


Fig. 3 Surge Current Derating Curve

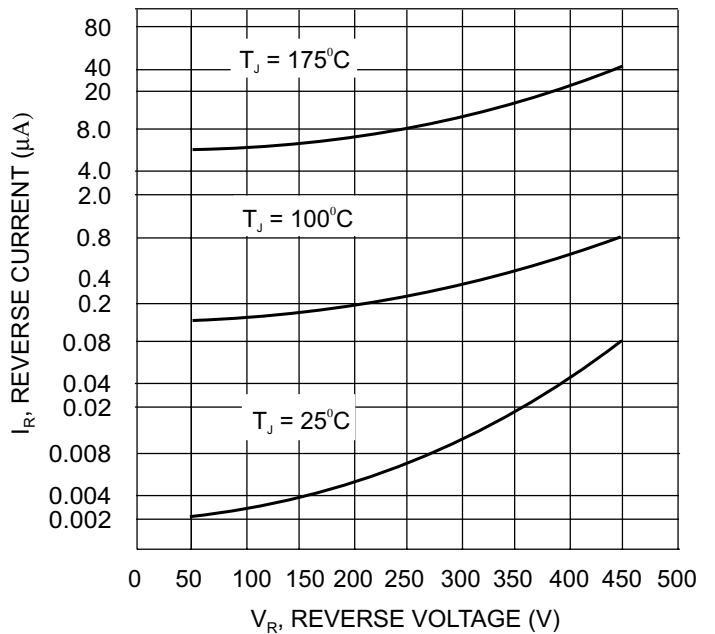
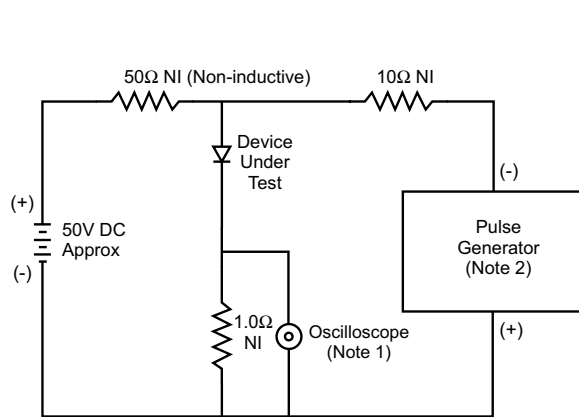
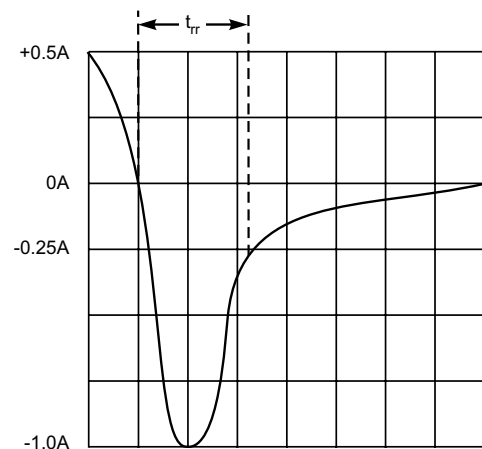


Fig. 4 Typical Reverse Current



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
  2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 50/100 ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit